SCAS032A - JULY 1987 - REVISED APRIL 1993

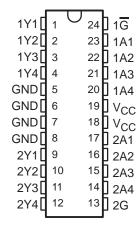
- 3-State Outputs Drive Bus Lines or Buffer Memory Address Registers
- Flow-Through Architecture Optimizes PCB Layout
- Center-Pin V_{CC} and GND Configurations
 Minimize High-Speed Switching Noise
- EPIC™ (Enhanced-Performance Implanted CMOS) 1-μm Process
- 500-mA Typical Latch-Up Immunity at 125°C
- Package Options Include Plastic Small-Outline Packages, Plastic Shrink Small-Outline Packages, Ceramic Chip Carriers, and Standard Plastic and Ceramic 300-mil DIPs

description

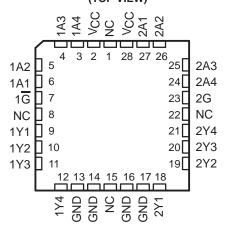
This octal buffer or line driver is designed specifically to improve both the performance and density of three-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters. Taken together with the AC11240 and AC11244, these devices provide the choice of selected combinations of inverting and noninverting outputs, symmetrical \overline{G} (active-low output control) inputs, and complementary G and \overline{G} inputs. This device features a high fan-out.

The 54AC11241 is characterized for operation over the full military temperature range of -55° C to 125°C. The 74AC11241 is characterized for operation from -40° C to 85° C.

54AC11241 ... JT PACKAGE 74AC11241 ... DB, DW OR NT PACKAGE (TOP VIEW)



54AC11241 . . . FK PACKAGE (TOP VIEW)



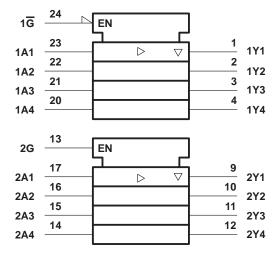
NC - No internal connection

FUNCTION TABLE

OUTPUT CONTROL 1G	DATA INPUT 1A	OUTPUT 1Y	OUTPUT CONTROL 2G	DATA INPUT 2A	OUTPUT 2Y
Н	Х	Z	L	Х	Z
L	L	L	Н	L	L
L	Н	Н	Н	Н	Н

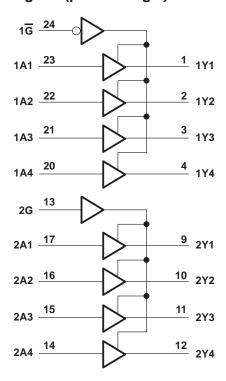
EPIC is a trademark of Texas Instruments Incorporated.

logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



Pin numbers shown are for the DW, JT, and NT packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V _{CC}	0.5 V to 7 V
Input voltage range, V _I (see Note 1)	\dots – 0.5 V to V _{CC} + 0.5 V
Output voltage range, V _O (see Note 1)	\dots -0.5 V to V _{CC} + 0.5 V
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$)	$\dots \dots \pm 20 \text{ mA}$
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CC})	± 50 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$	$\dots \dots \pm 50 \text{ mA}$
Continuous current through V _{CC} or GND	$\dots \dots \pm 200 \text{ mA}$
Storage temperature range	

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

recommended operating conditions

			54	4AC1124	1	74AC11241		LINUT	
			MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Vcc	Supply voltage		3	5	5.5	3	5	5.5	V
		V _{CC} = 3 V	2.1			2.1			
ViH	High-level input voltage	V _{CC} = 4.5 V	3.15			3.15			V
		V _{CC} = 5.5 V	3.85			3.85			
		VCC = 3 V			0.9			9.9	V
VIL	Low-level input voltage	V _{CC} = 4.5 V			1.35			1.35	
		V _{CC} = 5.5 V			1.65			1.65	
٧ı	Input voltage		0		Vcc	0		Vcc	V
٧o	Output voltage		0		Vcc	0		VCC	V
		VCC = 3 V			-4			-4	
ІОН	High-level output current	V _{CC} = 4.5 V			-24			-24	mA
		V _{CC} = 5.5 V			-24			-24	
	Low-level output current	VCC = 3 V			12			12	
lOL		$V_{CC} = 4.5 \text{ V}$			24			24	mA
		V _{CC} = 5.5 V			24			24	
Δt/Δν	Input transition rise or fall rate	Data	0		10	0		10	no/\/
Δι/Δν	Input transition rise or fall rate	G	0		5	0		5	ns/V
TA	Operating free-air temperature		-55		125	-40		85	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST COMPITIONS		T _A = 25°C			54AC	11241	74AC11241		
PARAMETER	TEST CONDITIONS	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
	Ι _{ΟΗ} = – 50 μΑ	3 V	2.9			2.9		2.9		
		4.5 V	4.4			4.7		4.4		
		5.5 V	5.4			5.4		5.4		
\/a	I _{OH} = - 4 mA	3 V	2.58			2.4		2.48		V
VOH	lou - 24 mA	4.5 V	3.94			3.7		3.8		V
	$I_{OH} = -24 \text{ mA}$	5.5 V	4.94			4.7		4.8]
	$I_{OH} = -50 \text{ mA}^{\dagger}$	5.5 V				3.85				
	$I_{OH} = -75 \text{ mA}^{\dagger}$	5.5 V						3.85		
	I _{OL} = 50 μA	3 V			0.1		0.1		0.1	
		4.5 V			0.1		0.1		0.1	
		5.5 V			0.1		0.1		0.1	
\/o:	I _{OL} = 12 mA	3 V			0.36		0.5		0.44	V
VOL	lo: - 24 mA	4.5 V			0.36		0.5		0.44	V
	I _{OL} = 24 mA	5.5 V			0.36		0.5		0.44	
	$I_{OL} = 50 \text{ mA}^{\dagger}$	5.5 V					1.65			
	$I_{OL} = 75 \text{ mA}^{\dagger}$	5.5 V							1.65	
loz	$V_O = V_{CC}$ or GND	5.5 V			± 0.5		± 10		± 5	μΑ
lį	$V_I = V_{CC}$ or GND	5.5 V			± 0.1		± 1		± 1	μΑ
l _{CC}	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			8		160		80	μΑ
C _i	$V_I = V_{CC}$ or GND	5 V		4						pF
Co	$V_O = V_{CC}$ or GND	5 V		10						pF

[†] Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.



54AC11241, 74AC11241 OCTAL BUFFERS/LINE DRIVERS WITH 3-STATE OUTPUTS

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switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	ТО	T _A = 25°C			54AC11241		74AC11241		UNIT	
PARAMETER	(INPUT)	(OUTPUT)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT	
t _{PLH}	А	Υ	V	1.5	7	10	1.5	12.2	1.5	11.4	ns
t _{PHL}	A		1.5	6.2	8.4	1.5	10.2	1.5	9.2		
^t PZH	- -	Υ	1.5	7.8	11.4	1.5	13.8	1.5	12.9	no	
tPZL	G or G		1.5	7.7	10.6	1.5	12.6	1.5	11.7	ns	
t _{PHZ}	G or G	V	1.5	5.8	7.6	1.5	8.2	1.5	7.9	no	
tPLZ	G or G	ī	1.5	7.1	9.3	1.5	10.3	1.5	9.9	ns	

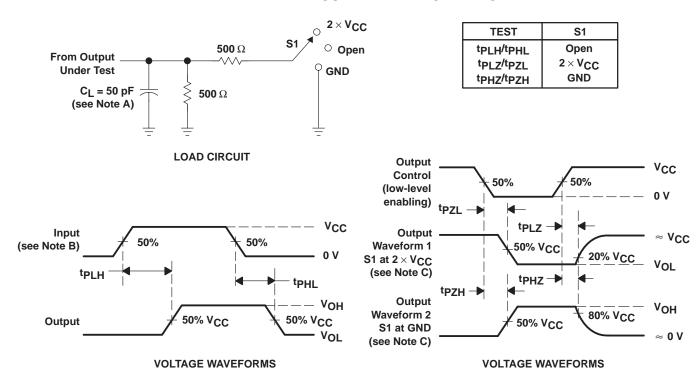
switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	T _A = 25°C			54AC11241		74AC11241		UNIT	
PARAMETER	(INPUT)	(OUTPUT)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT	
^t PLH	Α	Y	1.5	4.9	7.1	1.5	8.5	1.5	8	no	
^t PHL	A		1.5	4.5	6.3	1.5	7.2	1.5	6.8	ns	
^t PZH	G or G	Y	V	1.5	5.4	8	1.5	9.7	1.5	9	200
tpZL	G or G		1.5	5.3	7.6	1.5	9	1.5	8.4	ns	
^t PHZ	G or G	Y	1.5	4.9	6.6	1.5	7.2	1.5	6.9	ne	
tPLZ	G or G		1.5	5.6	7.5	1.5	8.3	1.5	8	ns	

operating characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER			TEST CON	TYP	UNIT	
C . Down discipation conscitones now huffer	Outputs enabled	C: F0 pF	f 4 MALI-	26		
Cbq	Power dissipation capacitance per buffer	Outputs disabled	$C_L = 50 \text{ pF},$	f = 1 MHz	10	pF

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_I includes probe and jig capacitance.

- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f = 3 \text{ ns}$, $t_f = 3 \text{ ns}$.
- C. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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